CMOS Digital Integrated Circuits Silicon Monolithic

74HC240D,74HC244D

1. Functional Description

Octal Bus Buffer
 74HC240D: INVERTED, 3-STATE OUTPUTS
 74HC244D: NON-INVERTED, 3-STATE OUTPUTS

2. General

 $The~74HC240D~and~74HC244D~are~high~speed~CMOS~OCTAL~BUS~BUFFERs~fabricated~with~silicon~gate~C^2MOS~technology.$

They achieve the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

The 74HC240D is an inverting 3-state buffer and the 74HC244D are non-inverting 3-state buffers having two active-low output enables.

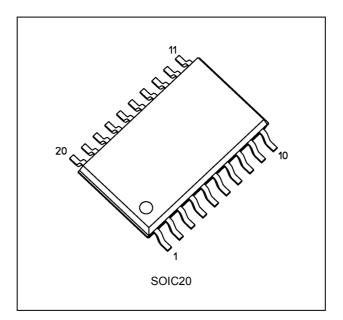
These devices are designed to be used with 3-state memory address drivers, etc.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

3. Features

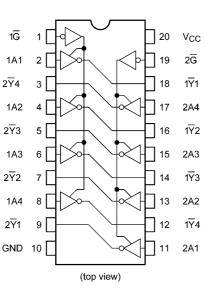
- (1) Wide operating temperature range: $T_{opr} = -40$ to 125 °C (Note 1)
- (2) High speed: $t_{pd} = 10$ ns (typ.) at $V_{CC} = 6.0$ V
- (3) Low power dissipation: $I_{CC} = 4.0 \ \mu A \ (max)$ at $T_a = 25 \ ^{\circ}C$
- (4) Balanced propagation delays: $t_{PLH} \approx t_{PHL}$
- (5) Wide operating voltage range: $V_{CC(opr)} = 2.0 \text{ V to } 6.0 \text{ V}$
- Note1 1:Operating Range spec of $T_{opr} = -40$ °C to 125 °C is applicable only for the products which manufactured after July 2020.

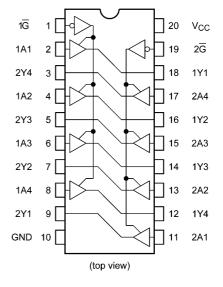
4. Packaging



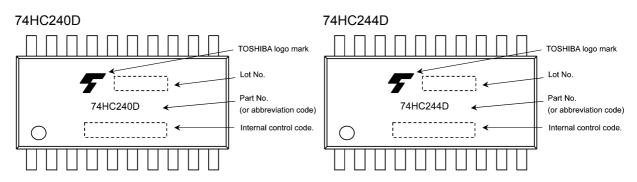
5. Pin Assignment

74HC240D



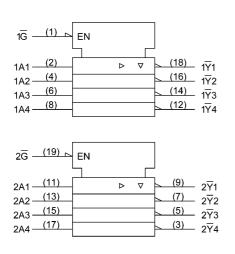


6. Marking



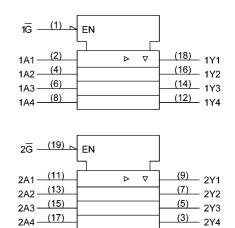
7. IEC Logic Symbol

74HC240D



74HC244D

74HC244D



8. Truth Table

Input G	Input An	Output Yn	Output Yn
L	L	L	Н
L	Н	Н	L
Н	Х	Z	Z

X: Don't care

Z: High impedance

Yn: 74HC244D

Yn: 74HC240D

9. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		-0.5 to 7.0	V
Input voltage	V _{IN}		-0.5 to V _{CC} + 0.5	V
Output voltage	V _{OUT}		-0.5 to V _{CC} + 0.5	V
Input diode current	I _{IK}		±20	mA
Output diode current	I _{OK}		±20	mA
Output current	I _{OUT}		±35	mA
V _{CC} /ground current	I _{CC}		±75	mA
Power dissipation	PD	(Note 1)	500	mW
Storage temperature	T _{stg}		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: P_D derates linearly with -8 mW/°C above 85 °C

10. Operating Ranges (Note)

Characteristics	Symbol	Test Condition	Note	Rating	Unit
Supply voltage	V _{CC}			2.0 to 6.0	V
Input voltage	V _{IN}			0 to V _{CC}	V
Output voltage	V _{OUT}			0 to V _{CC}	V
Operating temperature	T _{opr}		(Note 1)	-40 to 125	°C
Input rise and fall times	t _r ,t _f	V _{CC} = 2.0 V		0 to 1000	ns
		V _{CC} = 4.5 V		0 to 500	
		V _{CC} = 6.0 V		0 to 400	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

Note 1: Operating Range spec of T_{opr} = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.

11. Electrical Characteristics

11.1. DC Characteristics (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Тур.	Max	Unit
High-level input voltage	V _{IH}	_		2.0	1.50	_	_	V
				4.5	3.15	_	_]
				6.0	4.20	_	_	
Low-level input voltage	VIL	—		2.0	_	_	0.50	V
				4.5	_	—	1.35	
				6.0	_	_	1.80	
High-level output voltage	V _{OH}	$V_{IN} = V_{IH}$ or V_{IL}	I _{OH} = -20 μA	2.0	1.9	2.0	_	V
				4.5	4.4	4.5	_	
				6.0	5.9	6.0	_	
			I _{OH} = -6 mA	4.5	4.18	4.31		
			I _{OH} = -7.8 mA	6.0	5.68	5.80	_	
Low-level output voltage	V _{OL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OL} = 20 μA	2.0	_	0.0	0.1	V
				4.5		0.0	0.1	
				6.0	_	0.0	0.1	
			I _{OL} = 6 mA	4.5	_	0.17	0.26	
			I _{OL} = 7.8 mA	6.0	_	0.18	0.26	
3-state output OFF-state leakage current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = V _{CC} or GND		6.0	_	—	±0.5	μA
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND		6.0	_	_	±0.1	μA
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		6.0			4.0	μA

11.2. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
High-level input voltage	VIH	—		2.0	1.50	_	V
				4.5	3.15	_]
				6.0	4.20	—	
Low-level input voltage	V _{IL}	—		2.0		0.50	V
				4.5	_	1.35	
				6.0	_	1.80	
High-level output voltage	V _{OH}	$V_{IN} = V_{IH}$ or V_{IL}	I _{OH} = -20 μA	2.0	1.9	—	
				4.5	4.4	—	
				6.0	5.9	—	
			I _{OH} = -6 mA	4.5	4.13	—	
			I _{OH} = -7.8 mA	6.0	5.63	—	
Low-level output voltage	V _{OL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OL} = 20 μA	2.0	_	0.1	~
				4.5	—	0.1	
				6.0	_	0.1	
			I _{OL} = 6 mA	4.5	_	0.33	
			I _{OL} = 7.8 mA	6.0	—	0.33	
3-state output OFF-state leakage current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or } GND$		6.0	_	±5.0	μA
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND		6.0	_	±1.0	μA
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		6.0		40.0	μA

11.3. DC Characteristics (Note) (Unless otherwise specified, $T_a = -40$ to 125 °C)

Characteristics	Symbol	Test Condition	n	V _{CC} (V)	Min	Max	Unit
High-level input voltage	V _{IH}	—		2.0	1.50	—	V
				4.5	3.15	_	
				6.0	4.20	_]
Low-level input voltage	V _{IL}	—		2.0	_	0.50	V
				4.5	_	1.35	
				6.0	_	1.80]
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -20 μA	2.0	1.9	_	V
				4.5	4.4	_	
				6.0	5.9	_	
			I _{OH} = -6 mA	4.5	3.7	_	
			I _{OH} = -7.8 mA	6.0	5.2	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 20 μA	2.0	_	0.1	V
				4.5	_	0.1	
				6.0	_	0.1	
			I _{OL} = 6 mA	4.5	_	0.4]
			I _{OL} = 7.8 mA	6.0	_	0.4	
3-state output OFF-state leakage current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = V _{CC} or GND		6.0	_	±5.0	μA
Input leakage current	I _{IN}	$V_{IN} = V_{CC}$ or GND		6.0	_	±1.0	μA
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		6.0		80.0	μA

Note: Operating Range spec of T_{opr} = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.

11.4. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 6$ ns)

Characteristics	Part Number	Symbol	Note	Test Condition	C _L (pF)	V _{CC} (V)	Min	Тур.	Max	Unit
Output transition time		t _{TLH} ,t _{THL}			50	2.0	—	25	60	ns
						4.5	_	7	12	
						6.0		6	10	
Propagation delay time		t _{PLH} ,t _{PHL}			50	2.0		36	90	ns
						4.5		12	18	
						6.0		10	15	
					150	2.0		51	130	
						4.5		17	26	
						6.0		14	22	
Output enable time		t _{PZL} ,t _{PZH}		R _L = 1 kΩ	50	2.0	_	48	125	ns
						4.5		16	25	
						6.0		14	21	
					150	2.0		63	165	
						4.5		21	33	
						6.0		18	28	
Output disable time		t _{PLZ} ,t _{PHZ}		R_L = 1 k Ω	50	2.0		32	125	ns
						4.5		15	25	
						6.0		14	21	
Input capacitance		C _{IN}		_				5	10	pF
Output capacitance		C _{OUT}		_				10	_	pF
Power dissipation	74HC240D	C _{PD}	(Note 1)	—				31	_	pF
capacitance	74HC244D							33	_	

Note 1: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation. $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/8$ (per bit)

11.5. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Test Condition	C _L (pF)	V _{CC} (V)	Min	Max	Unit
Output transition time	t _{TLH} ,t _{THL}	—	50	2.0	—	75	ns
				4.5	_	15	
				6.0	_	13	
Propagation delay time	t _{PLH} ,t _{PHL}	_	50	2.0	_	115	ns
				4.5	_	23	
				6.0	_	20	
			150	2.0	_	165	
				4.5	—	33	
				6.0	_	28	
Output enable time	t _{PZL} ,t _{PZH}	R _L = 1 kΩ	50	2.0	_	155	ns
				4.5	_	31	
				6.0	_	26	
			150	2.0	_	205	
				4.5	_	41	
				6.0	_	35	
Output disable time	t _{PLZ} ,t _{PHZ}	R _L = 1 kΩ	50	2.0	_	155	ns
				4.5		31]
				6.0	_	26	
Input capacitance	C _{IN}				_	10	pF

11.6. AC Characteristics (Note) (Unless otherwise specified, T_a = -40 to 125 °C, Input: t_r = t_f = 6 ns)

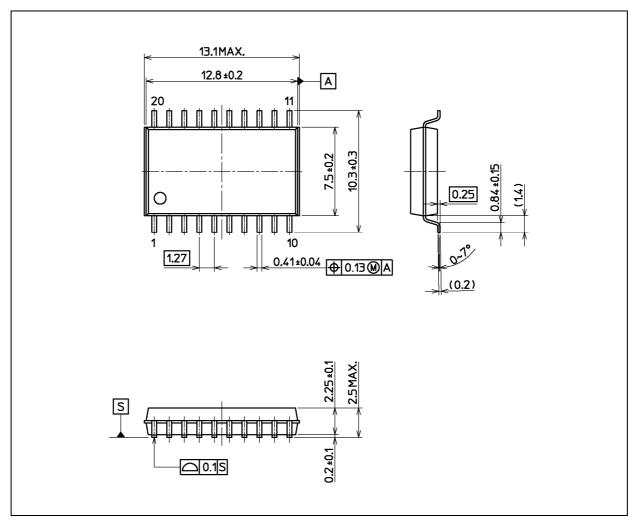
Characteristics	Symbol	Test Condition	C _L (pF)	V _{CC} (V)	Min	Max	Unit
Output transition time	t _{TLH} ,t _{THL}	_	50	2.0	—	85	ns
				4.5	_	17	
				6.0	_	15	1
Propagation delay time	t _{PLH} ,t _{PHL}	_	50	2.0	_	135	ns
				4.5	_	27]
				6.0	_	24	1
			150	2.0	_	190	1
				4.5	_	38]
				6.0	_	32	1
Output enable time	t _{PZL} ,t _{PZH}	R _L = 1 kΩ	50	2.0	_	175	ns
				4.5	_	35]
				6.0	_	30]
			150	2.0	_	235]
				4.5	_	47]
				6.0	_	40	1
Output disable time	t _{PLZ} ,t _{PHZ}	R _L = 1 kΩ	50	2.0	_	175	ns
				4.5	_	35	
				6.0	_	30	
Input capacitance	C _{IN}	_	x		—	10	pF

Note: Operating Range spec of T_{opr} = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.



Package Dimensions

Unit: mm



Weight: 0.51 g (typ.)

Package Name(s)
Nickname: SOIC20

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